

BANGLADESH UNIVERSITY OF ENGINEERING AND TECHNOLOGY



Gate Driver Using HEMT GS66504B and ADuM4121A

Prepared by-

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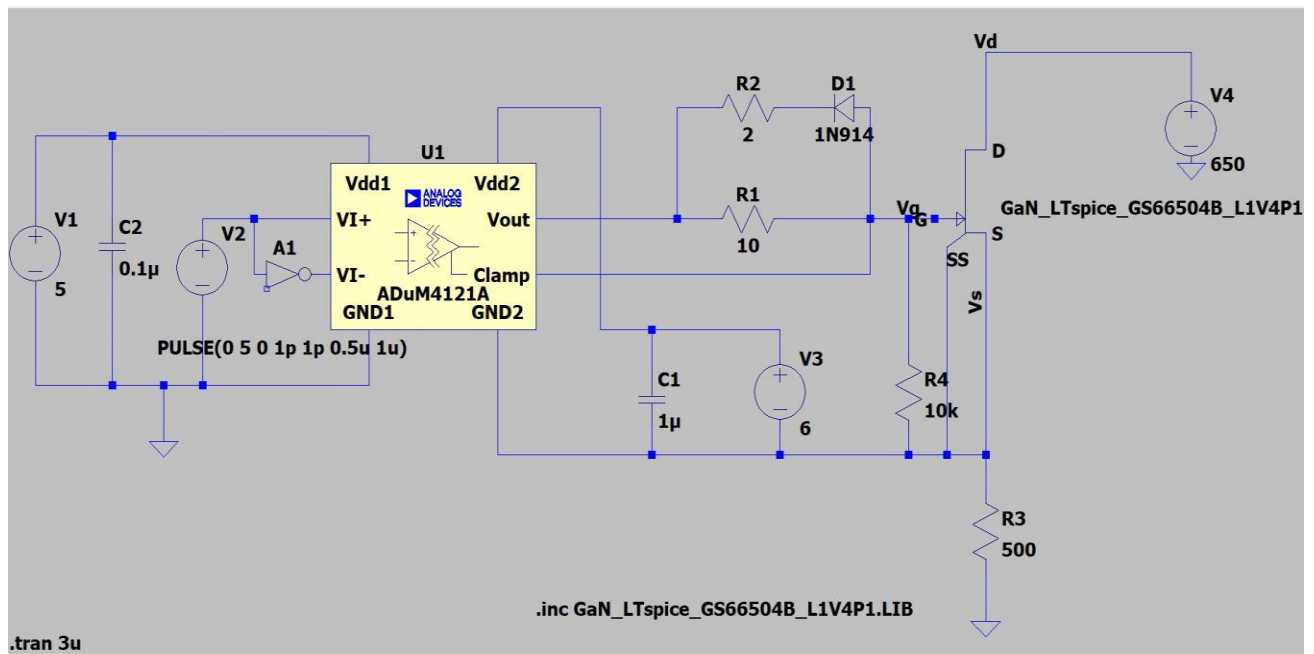
Submitted to-

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Schematic Diagram:



Here,

$$V_{IN} = 650V$$

$$\text{Load Resistor} = 500\Omega$$

$$\text{Switch_On_Current} = \frac{650}{500} = 1.3A$$

$$V_{\text{Pulse}} = \begin{cases} 0; & \text{Keeps gate voltage low} \\ 5; & \text{keeps gate voltage high} \end{cases}$$

$$V_{GS} = \begin{cases} 0; & \text{switch off} \\ 6; & \text{switch on} \end{cases}$$

Output:

At Switching Frequency = **500KHz**

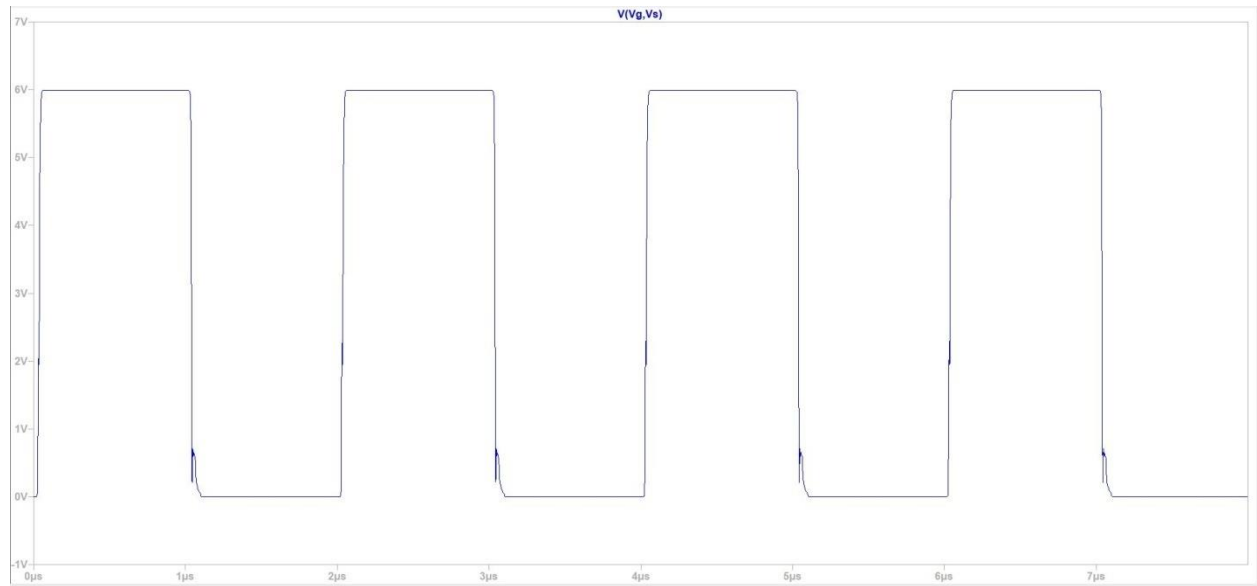
Turning ON, $\frac{dv}{dt} = \mathbf{79.2\ V/ns}$ (approx.)

Turning OFF, $\frac{dv}{dt} = \mathbf{4.17\ V/ns}$ (approx.)

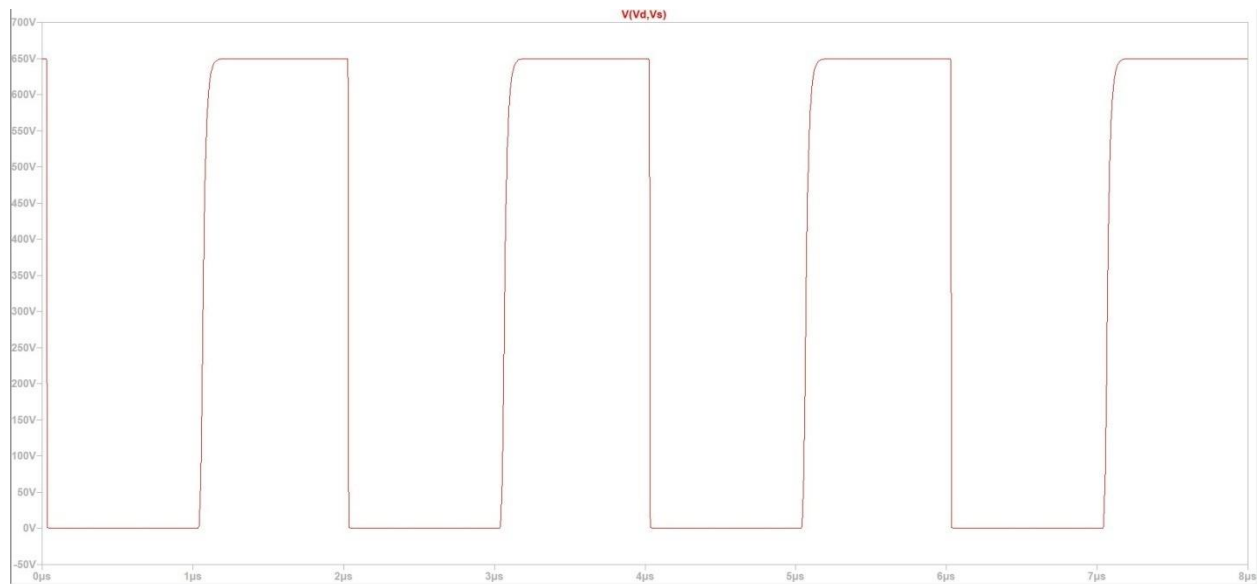
If, $V_{GS}=6\ V \rightarrow V_{DS}=0V$ & $I=1.3A$

If, $V_{GS}=0V \rightarrow V_{DS}=650V$ & $I=0A$

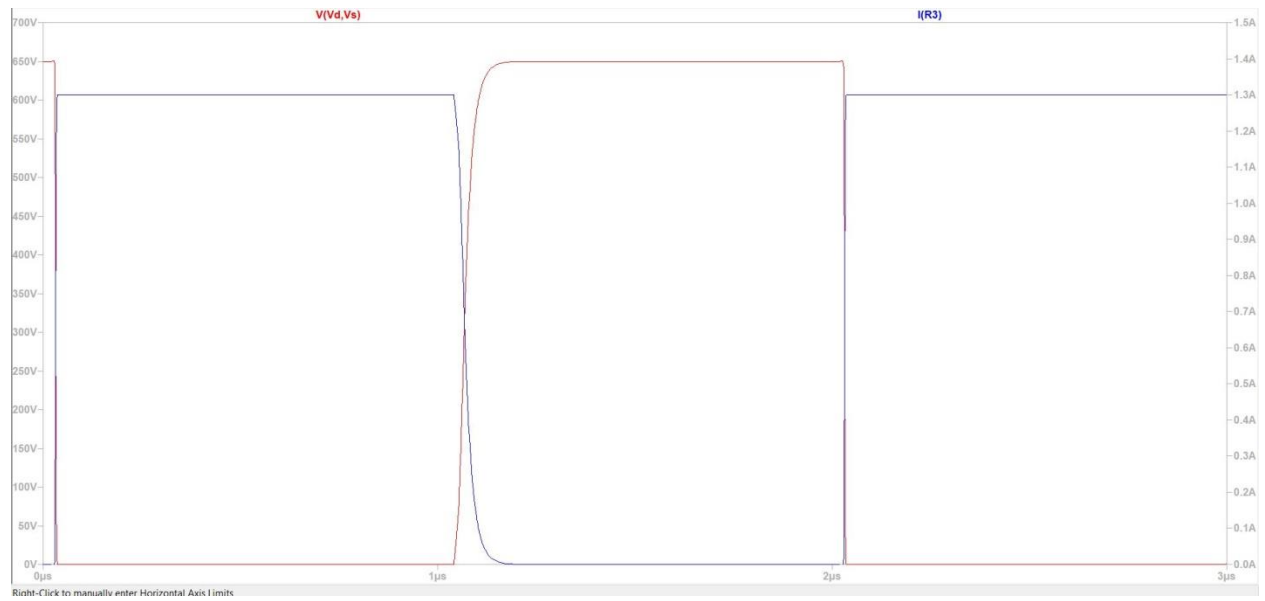
V_{GS} VS Time:



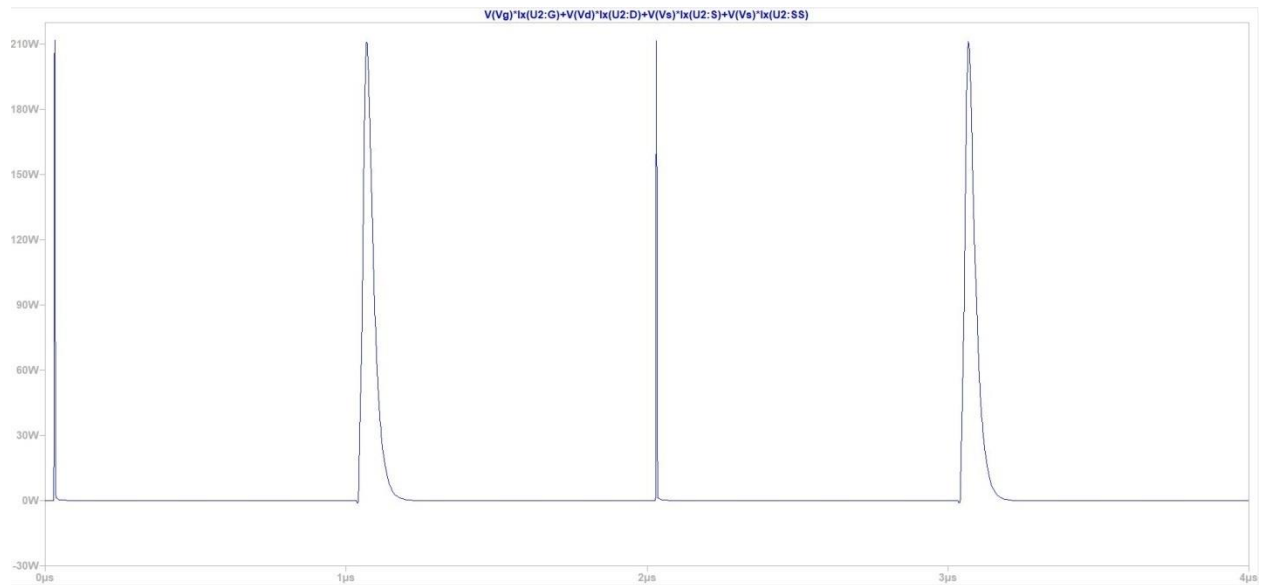
V_{DS} VS Time



V_{DS} & I_{load}



Powerloss VS Time



At Frequency = **1MHz**

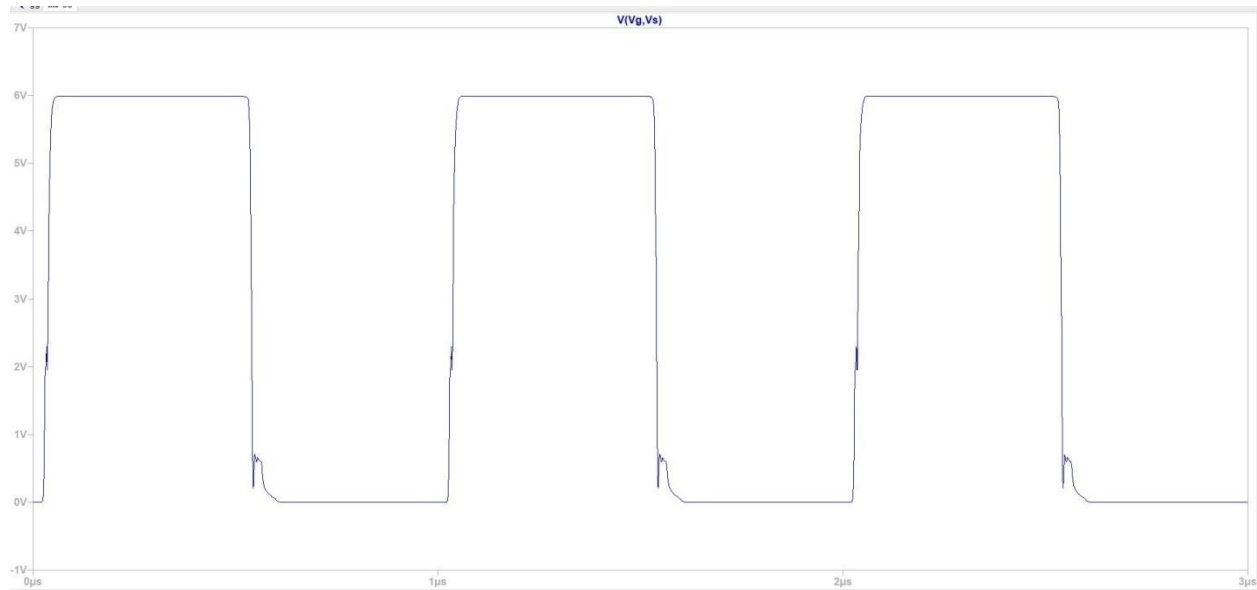
Turning ON, $\frac{dv}{dt} = \mathbf{76.2\ V/ns}$ (*approx.*)

Turning OFF, $\frac{dv}{dt} = \mathbf{4\ V/ns}$ (*approx.*)

If, $V_{GS}=6\ V \rightarrow V_{DS}=0V$ & $I=1.3A$

If, $V_{GS}=0V \rightarrow V_{DS}=650V$ & $I=0A$

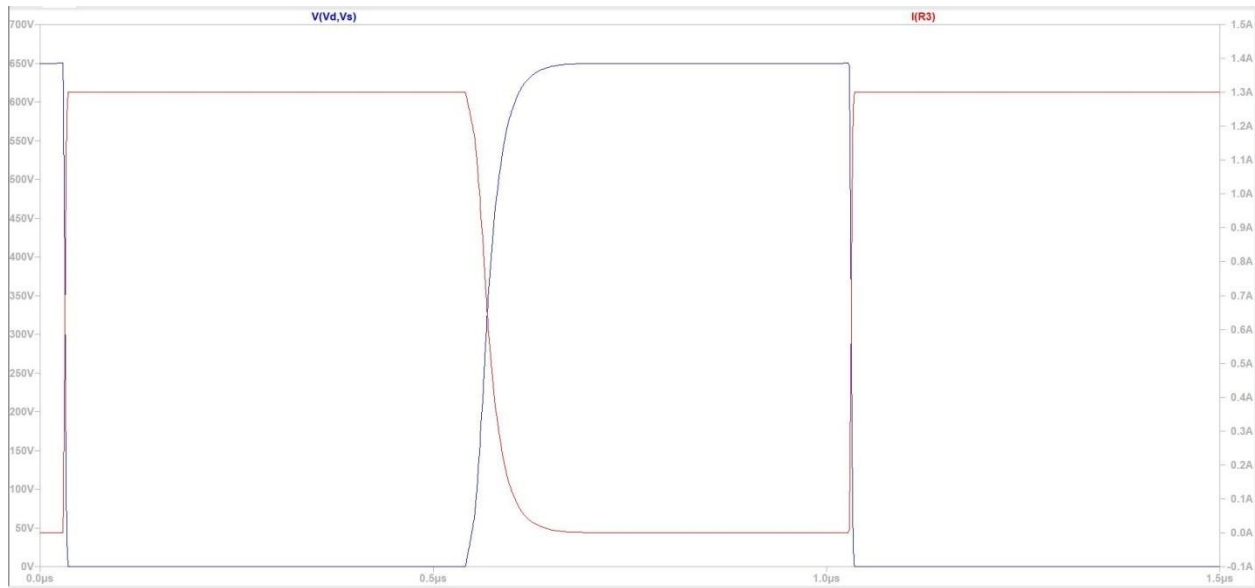
V_{GS} VS Time



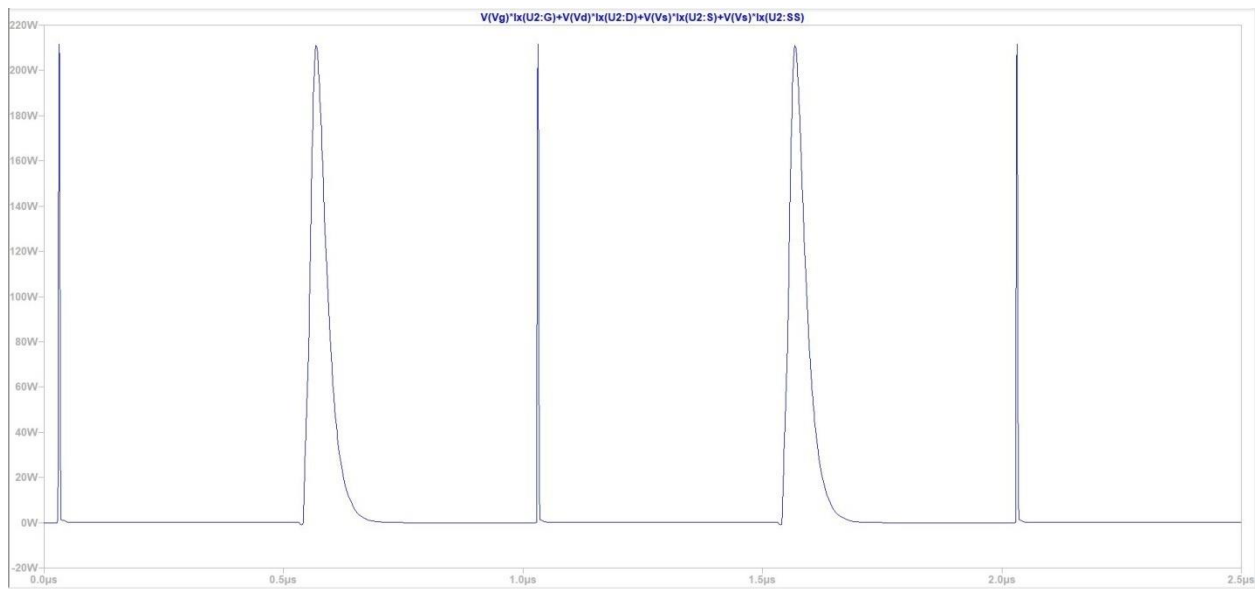
V_{DS} VS Time



V_{DS} & I_{Load}



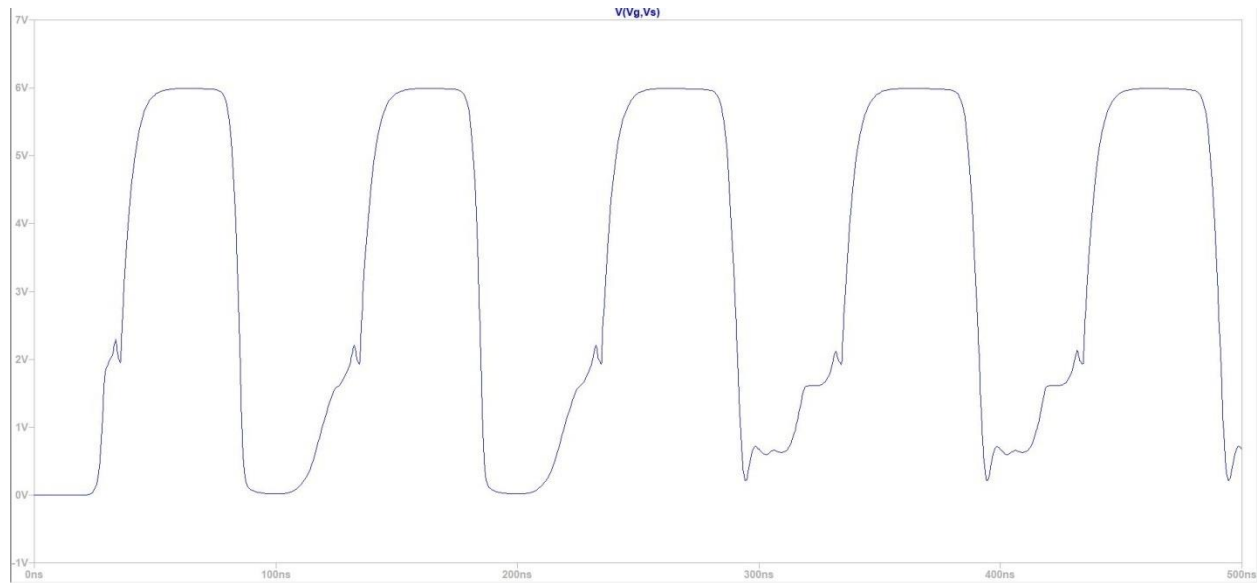
Switching_power_losses VS Time



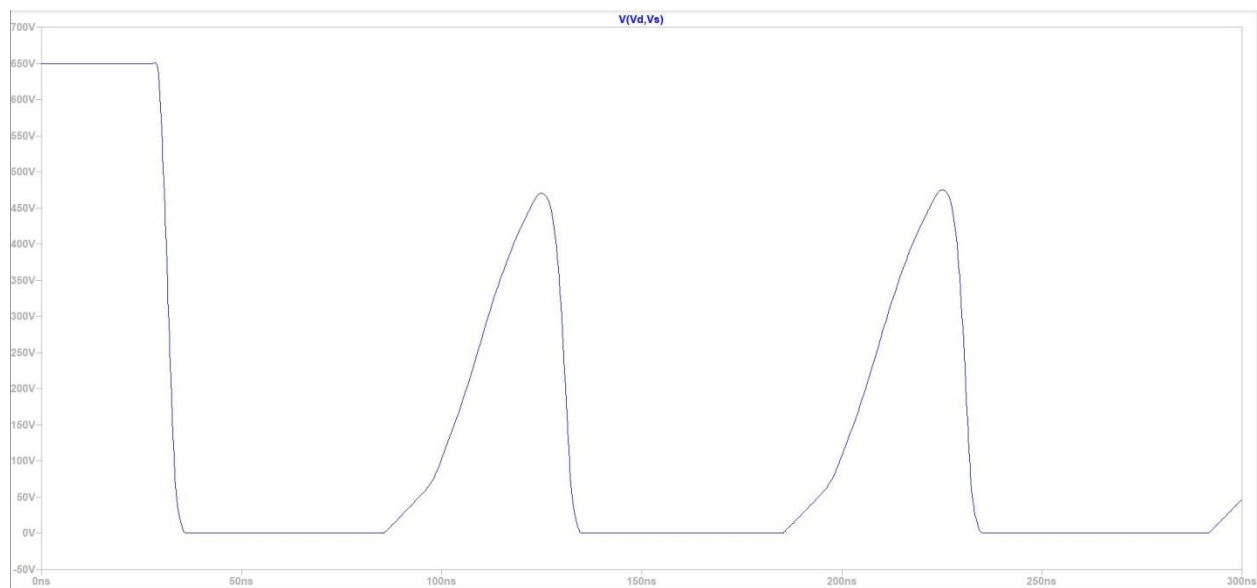
At Frequency= **10MHz**

Distorted output!!!

V_{GS} VS Time



V_{DS} VS Time



Switching_power_losses VS Time

